

N-Channel 30-V (D-S) MOSFET

Description

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low rDS(on) and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

Features

- Low rDS(on) trench technology
- · Low thermal impedance
- · Fast switching speed
- RoHS compliant package
- Typical Applications:
- White LED boost converters
- Automotive Systems

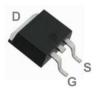
• Industrial DC/DC Conversion Circuits

Package type : TO-252

Packing & Order Information

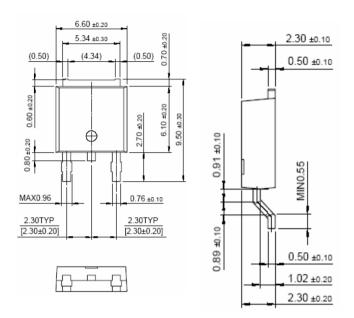
Part No./ T : 2,500/Reel

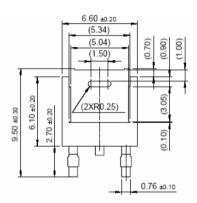
Part No./ R : 80/Tube, 4,000/Box



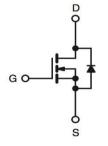


Graphic symbol





Graphic symbol



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings (T _A =25°C unless otherwise specified)					
Symbol	Parameter	Value	Unit		
V _{DS}	Drain-Source Voltage	30	V		
V _{GS}	Gate-Source Voltage	±20	V		
ID	Continuous Drain Current ^a (T _A =25°C)	75	А		
IDM	Pulsed Drain Current ^b	300	А		
Is	Continuous Source Current (Diode Conduction) ^a	30	А		



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Absolute Maximum Ratings (T _A =25°C unless otherwise specified)					
Symbol	Parameter Value		Unit		
PD	Power Dissipation ^a ($T_A = 25^{\circ}C$)	50	W		
T_J/T_{STG}	Operating Junction and Storage Temperature -55 to +175		°C		
Rөја	Maximum Junction-to-Ambient ^a (t <= 10 sec)	40	°C/W		
Rejc	Maximum Junction-to-Ambient ^a (Steady-State)	3			

Notes

a. Surface Mounted on 1" x 1" FR4 Board.

b. Pulse width limited by maximum junction temperature

Static							
Symbol	Parameter	Test Conditions	Min	Typ.	Max.	Units	
$V_{GS(th)}$	Gate-Source Threshold Voltage	$V_{\rm DS}=V_{\rm GS},I_{\rm D}=-250\mu A$	1			V	
I _{GSS}	Gate-Body Leakage	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			±100	nA	
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24 \ V \ , \ V_{GS} = 0 \ V$			1	uA	
		$V_{DS}=24~V~,~V_{GS}=0~V~,~T_J=55^\circ C$			25	uA	
ID(on)	On-State Drain Current	$V_{DS}=5\ V,\ V_{Gs}=10\ V$	120			A	
^r DS (on)	Drain-Source On-Resistance	$V_{DS} = 10 V, I_D = 20 A$			6	mΩ	
		$V_{GS} = 4.5 \text{ V}, I_D = 18 \text{ A}$			8		
g _{fs}	Forward Tranconductance	$V_{GS} = 15 \text{ V}, I_D = 20 \text{ A}$		20		S	
V _{SD}	Diode Forward Voltage	$I_S = 15 \ A \ , \ V_{GS} = 0 \ V$		0.84		V	

Dynamic						
Symbol	Parameter	Test Conditions	Min	Typ.	Max.	Units
Q_{g}	Total Gate Charge	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 20 \text{ A},$ 		20		nC
Q_{gs}	Gate-Source Charge			7.3		nC
Q_{gd}	Gate-Drain Charge			11		nC
t _{d(on)}	Turn-On Delay Time	$I_{D} = 20 \text{ A}, R_{L} = 0.8 \Omega,$ $V_{GEN} = 10 \text{ V}, R_{GEN} = 6 \Omega$ $V_{DS} = 15 \text{ V}$		10		ns
tr	Rise Time			13		ns
$t_{d(\mathrm{off})}$	Turn-Off Delay Time			51		ns
tf	Fall Time			21		ns
C _{ISS}	Input Capacitance	$ V_{DS} = 15 V f = 1 MHz , V_{GS} = 0 V $		1785		pF
Coss	Output Capacitance			323		pF
C _{RSS}	Reverse Transfer Capacitance			285		pF

Notes

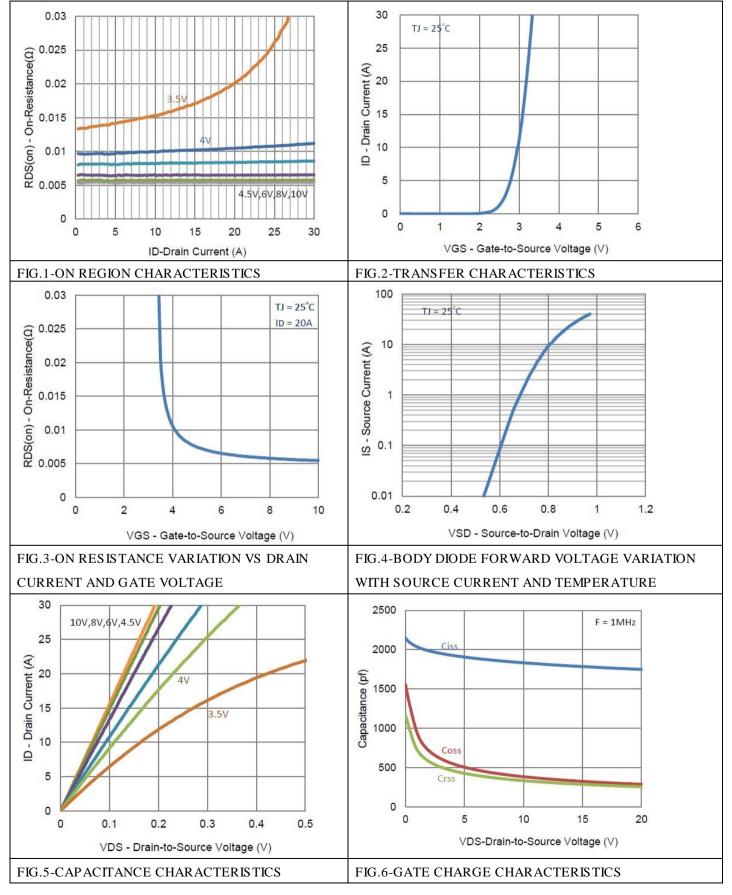
a. Pulse test: PW <= 300us duty cycle <= 2%.

b. Guaranteed by design, not subject to production testing.



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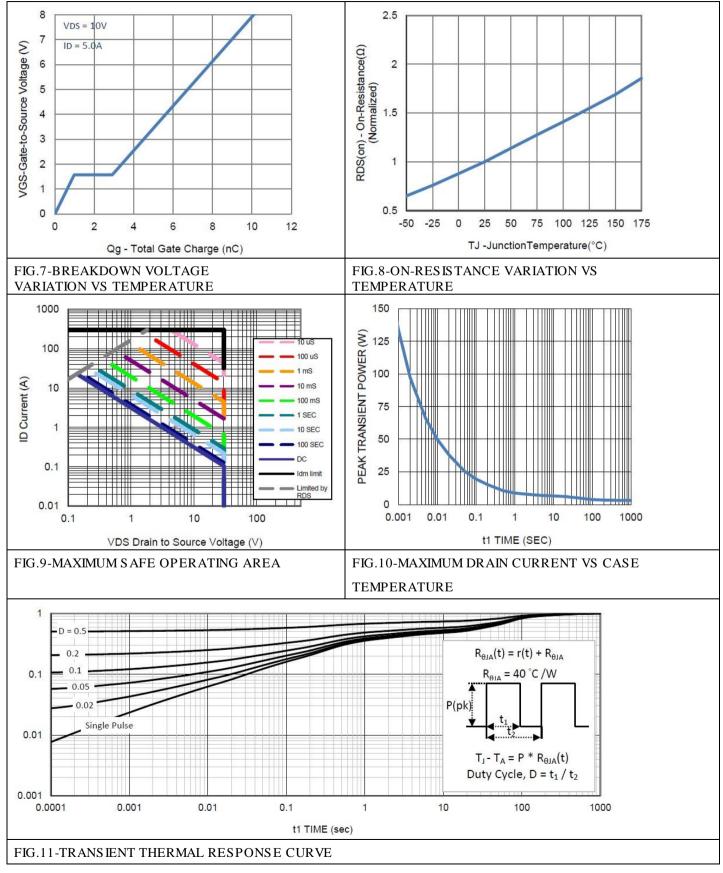
■Typical Electrical Characteristics





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Typical Electrical Characteristics





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